

40 V, 500 mA PNP loadswitch transistor

1 January 2023

Product data sheet

1. General description

PNP low V_{CEsat} transistor and NPN Resistor-Equipped Transistor (RET) in one very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low V_{CEsat} transistor and resistor-equipped transistor in one package
- Low threshold voltage (<1 V) compared to MOSFET
- Low drive power required
- Space-saving solution
- Reduction of component count

3. Applications

- Supply line switches
- Battery charger switches
- · High-side switches for LEDs, drivers and backlights
- Portable equipment

4. Quick reference data

Table 1. Quick reference data

		• •••		_		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1: PNP lo	ow V _{CEsat} transistor					
V _{CEO}	collector-emitter voltage	open base	-	-	-40	V
I _{Clim}	limiting collector current		-	-	-500	mA
R _{CEsat}	collector-emitter saturation resistance	$\begin{array}{l} I_{C}=\text{-500 mA;} \ I_{B}=\text{-50 mA;} \\ T_{amb}=25\ ^{\circ}\text{C;} \ pulsed; \ t_{p}\leq \ 300\ \mu\text{s;} \\ \delta_{factor}\leq \ 0.02 \end{array}$	-	440	700	mΩ
TR2: NPN r	esistor-equipped transistor	r		·		
V _{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		C1 I2 GND2
2	B1	base TR1	□6 □5 □4	
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	12	input (base) TR2		
6	C1	collector TR1	TSSOP6 (SOT363)	E1 B1 O2 sym036

6. Ordering information

Table 3. Ordering information Type number	Package				
	Name	Description	Version		
PBLS4002Y		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBLS4002Y	S2%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1: PNP lo	w V _{CEsat} transistor					
V _{CBO}	collector-base voltage	open emitter		-	-40	V
V _{CEO}	collector-emitter voltage	open base		-	-40	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _{Clim}	limiting collector current			-	-500	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	-1	mA
I _B	base current			-	-50	mA
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
TR2: NPN re	esistor-equipped transistor		I			
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage	input voltage TR2 positive		-	30	V
		input voltage TR2 negative		-	-10	V
I _O	output current			-	100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device			I			
P _{tot}	total power dissipation			-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Fable 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per device							
ui(j-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

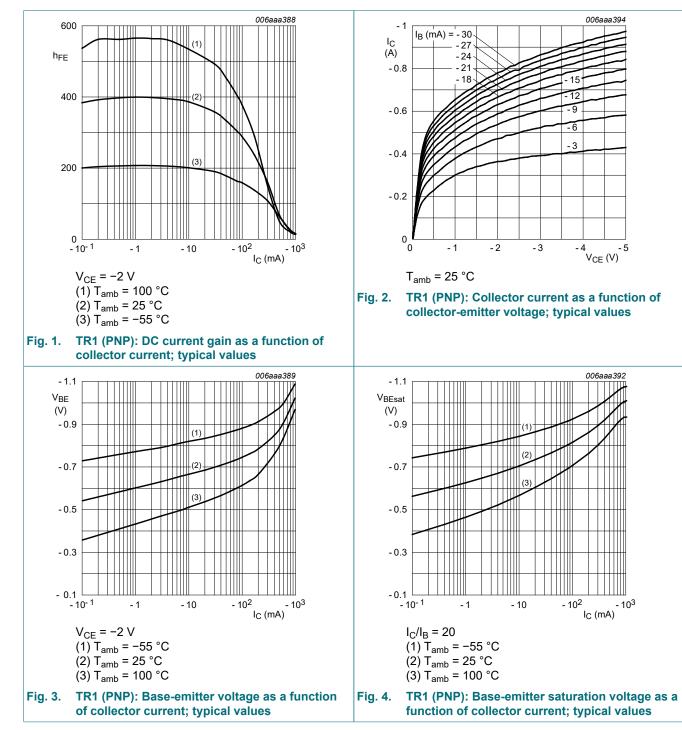
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1: PNP lo	w V _{CEsat} transistor					
V _{(BR)CBO}	collector-base breakdown voltage	I_{C} = -100 µA; I_{E} = 0 A; T_{amb} = 25 °C	-40	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -10 mA; I _B = 0 A; T _{amb} = 25 °C	-40	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _C = 0 A; I _E = 100 μA; T _{amb} = 25 °C	-6	-	-	V
I _{СВО}	collector-base cut-off	V _{CB} = -40 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -40 V; I _E = 0 A; T _{amb} = 150 °C	-	-	-50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 mA; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I _C = -10 mA; pulsed; T _{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I _C = -100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	150	-	-	
		V_{CE} = -2 V; I _C = -500 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	40	-	-	
V _{CEsat} collector-emitter saturation voltage		I _C = -10 mA; I _B = -0.5 mA; T _{amb} = 25 °C	-	-	-50	mV
	saturation voltage	I _C = -100 mA; I _B = -5 mA; T _{amb} = 25 °C	-	-	-130	mV
		I _C = -200 mA; I _B = -10 mA; T _{amb} = 25 °C	-	-	-200	mV
		I_{C} = -500 mA; I_{B} = -50 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02 %; T_{amb} = 25 °C	-	-	-350	mV
R _{CEsat}	collector-emitter saturation resistance	I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C; pulsed; t _p ≤ 300 µs;	-	440	700	mΩ
V _{BEsat}	base-emitter saturation voltage	δ _{factor} ≤ 0.02	-	-	-1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I _C = -100 mA; T _{amb} = 25 °C; pulsed; t _p ≤ 300 µs; $\delta_{factor} \le 0.02$	-	-	-1.1	V
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF
f _T	transition frequency	V _{CE} = -5 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C	100	300	-	MHz
TR2: NPN re	esistor-equipped transisto	ſ				
V _{(BR)CBO}	collector-base breakdown voltage	I_{C} = 100 µA; I_{E} = 0 A; T_{amb} = 25 °C	50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _B = 0 A; T _{amb} = 25 °C	50	-	-	V
сво	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
CEO	collector-emitter cut-off	$V_{CE} = 50 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C}$	-	-	1	μA
	current	V _{CE} = 50 V; I _B = 0 A; T _{amb} = 150 °C	-	-	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	900	μA
h _{FE}	DC current gain	V_{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA; T_{amb} = 25 °C	-	-	150	mV

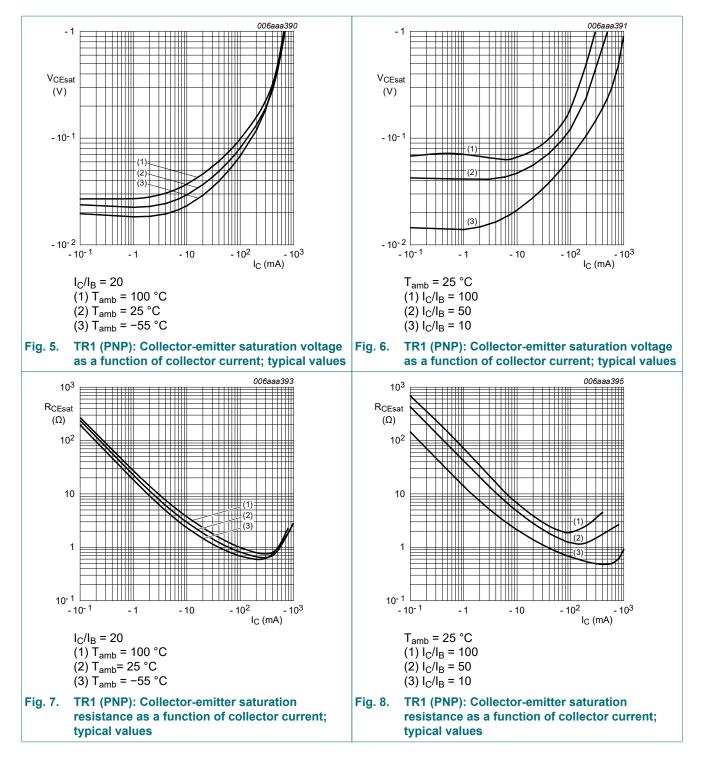
PBLS4002Y

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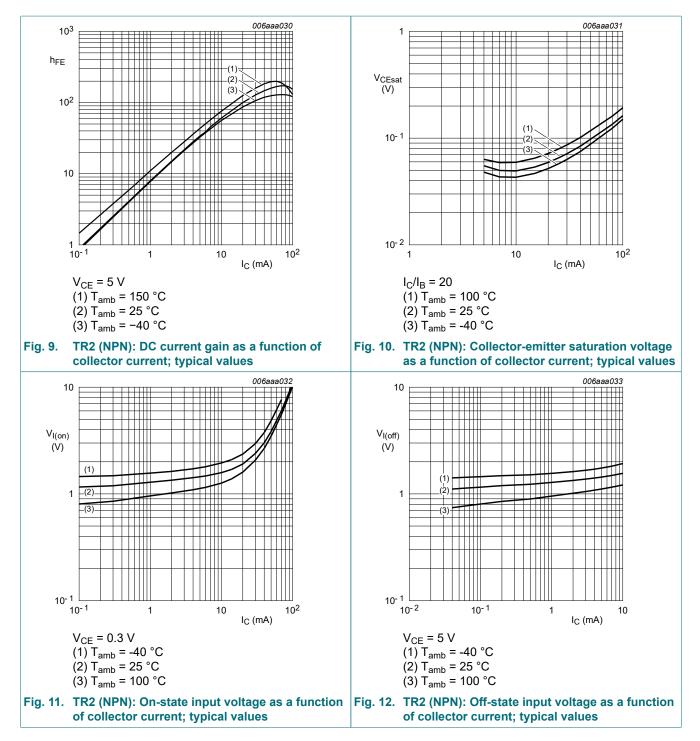
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I _C = 100 µA; T _{amb} = 25 °C	-	1.1	0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = 0.3 V; I _C = 20 mA; T _{amb} = 25 °C	2.5	1.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	-	-	2.5	pF



40 V, 500 mA PNP loadswitch transistor



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11. Test information

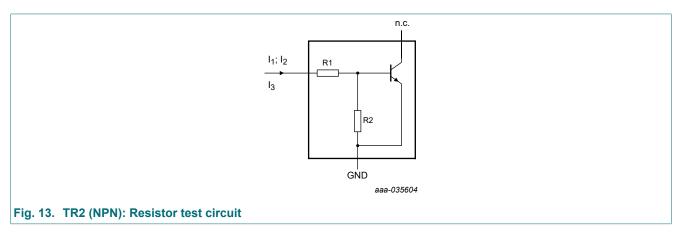
Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{Rl} = \frac{V(I3)}{Rl \cdot I3} - 1$$

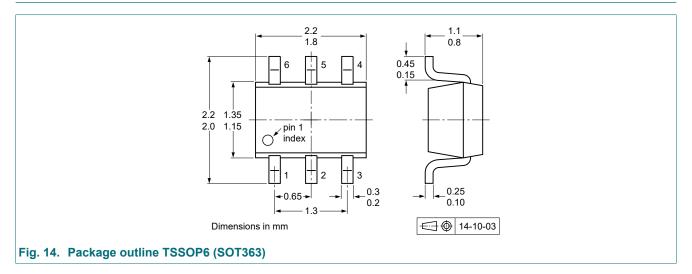


Resistor test conditions

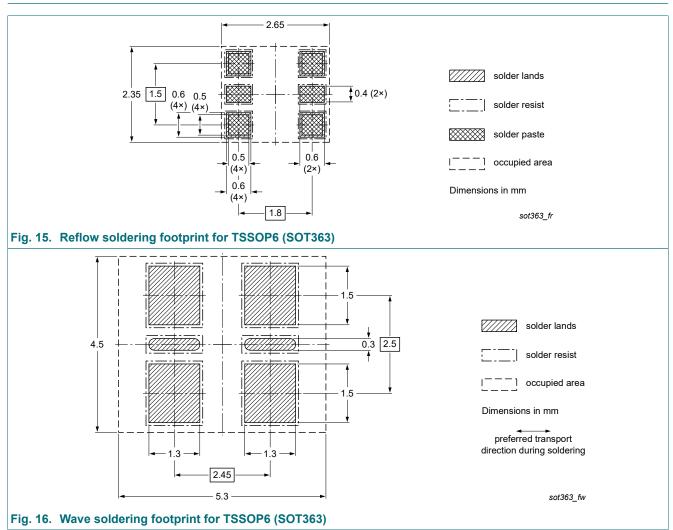
Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions				
			l ₁	l ₂	l ₃		
Per transistor, for the PNP with negative polarity							
PBLS4002Y	4.7	4.7	750 µA	950 µA	850 µA		

12. Package outline



13. Soldering



PBLS4002Y

14. Revision history

Table 9. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBLS4002Y v.5	20230101	Product data sheet	-	PBLS4002Y v.4			
Modifications:		Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).					
PBLS4002Y v.4	20220427	Product data sheet	-	PBLS4002Y_PBLS4002V_3			
PBLS4002Y_PBLS4002V_3	20090212	Product data sheet	-	PBLS4002Y_PBLS4002V_2			
PBLS4002Y_PBLS4002V_2	20050719	Product data sheet	-	PBLS4002Y_PBLS4002V_1			
PBLS4002Y_PBLS4002V_1	20041206	Product data sheet	-	-			

PBLS4002Y

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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